

Stud-Mounted Silicon Rectifier Diodes, 15 A



DO-203AB (DO-5)

DESCRIPTION/FEATURES

- Low thermal impedance
- High case temperature
- Excellent reliability
- Maximum design flexibility
- Can be made to meet stringent military, aerospace and other high reliability requirements
- Compliant to RoHS directive 2002/95/EC



RoHS
COMPLIANT

PRODUCT SUMMARY

$I_{F(AV)}$	15 A
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MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{F(AV)}$		15 ⁽¹⁾	A
	T_C	150 ⁽¹⁾	°C
I_{FSM}	50 Hz	239	A
	60 Hz	250 ⁽¹⁾	
I^2t	50 Hz	286	A ² s
	60 Hz	260	
$I^2\sqrt{t}$		3870	A ² √s
V_{RRM}	Range	50 to 600	V
T_J		- 65 to 175	°C

Note

⁽¹⁾ JEDEC registered values

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE ($T_J = - 65\text{ °C TO }175\text{ °C}$) V	V_{RM} , MAXIMUM DIRECT REVERSE VOLTAGE ($T_J = - 65\text{ °C TO }175\text{ °C}$) V
1N3208	50 ⁽¹⁾	50 ⁽¹⁾
1N3209	100 ⁽¹⁾	100 ⁽¹⁾
1N3210	200 ⁽¹⁾	200 ⁽¹⁾
1N3211	300 ⁽¹⁾	300 ⁽¹⁾
1N3212	400 ⁽¹⁾	400 ⁽¹⁾
1N3213	500 ⁽¹⁾	500 ⁽¹⁾
1N3214	600 ⁽¹⁾	600 ⁽¹⁾

Notes

⁽¹⁾ JEDEC registered values

- Basic type number indicates cathode to case. For anode to case, add "R" to part number, e.g. 1N3208R, 1N3209R

FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current at case temperature	I _{F(AV)}	180° sinusoidal conduction		15 ⁽¹⁾	A	
				150 ⁽¹⁾	°C	
Maximum peak one cycle non-repetitive surge current	I _{FSM}	Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with rated V _{RRM} applied	239	A	
		Half cycle 60 Hz sine wave or 5 ms rectangular pulse		250 ⁽¹⁾		
		Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with V _{RRM} applied following surge = 0	284		
		Half cycle 60 Hz sine wave or 5 ms rectangular pulse		297		
Maximum I ² t for fusing	I ² t	t = 10 ms	With rated V _{RRM} applied following surge, initial T _J = 150 °C	286	A ² s	
		t = 8.3 ms		260		
Maximum I ² t for individual device fusing		t = 10 ms	With V _{RRM} = 0 following surge, initial T _J = 150 °C	403		
		t = 8.3 ms		368		
Maximum I ² √t for individual device fusing	I ² √t ⁽²⁾	t = 0.1 ms to 10 ms, V _{RRM} = 0 following surge		3870	A ² √s	
Maximum forward voltage drop	V _{FM}	I _{F(AV)} = 15 A (47.1 A peak), T _C = 150 °C		1.5 ⁽¹⁾	V	
Maximum average reverse current	I _{R(AV)}	Maximum rated I _{F(AV)} and T _C = 150 °C		10 ⁽¹⁾	mA	

Notes⁽¹⁾ JEDEC registered values⁽²⁾ I^2t for time $t_x = I^2\sqrt{t} \times \sqrt{t_x}$

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction operating and storage temperature range	T _J , T _{Stg}		- 65 to 175 ⁽¹⁾	°C
Maximum internal thermal resistance, junction to case	R _{thJC}	DC operation	0.65	°C/W
Thermal resistance, case to sink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25	
Maximum allowable mounting torque (+ 0 %, - 10 %)		Not lubricated thread, tightening on nut ⁽²⁾	3.4 (30)	
		Lubricated thread, tightening on nut ⁽²⁾	2.3 (20)	
		Not lubricated thread, tightening on hexagon ⁽³⁾	4.2 (37)	
		Lubricated thread, tightening on hexagon ⁽³⁾	3.2 (28)	
Weight			28.5	g
			1	oz.
Case style		JEDEC	DO-203AB (DO-5)	

Notes⁽¹⁾ JEDEC registered values⁽²⁾ Recommended for pass-through holes⁽³⁾ Recommended for holed threaded heatsinks

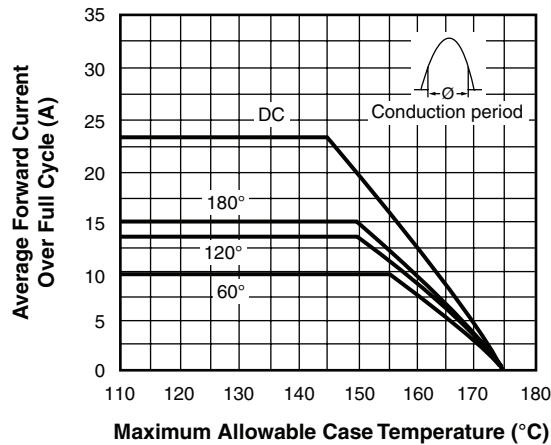


Fig. 1 - Average Forward Current vs. Maximum Allowable Case Temperature

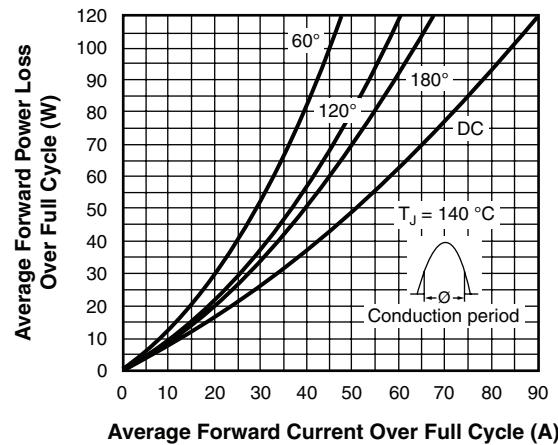


Fig. 3 - Maximum Low Level Forward Power Loss vs. Average Forward Current

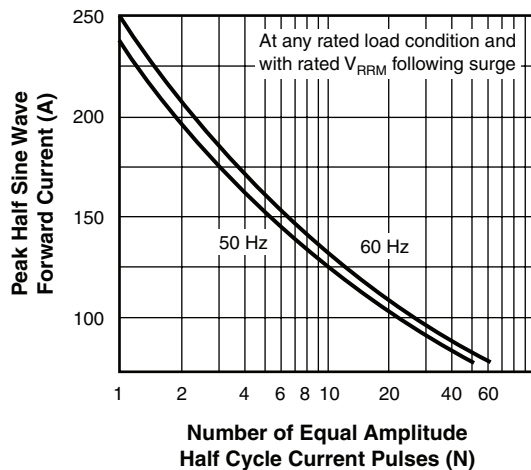


Fig. 2 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses

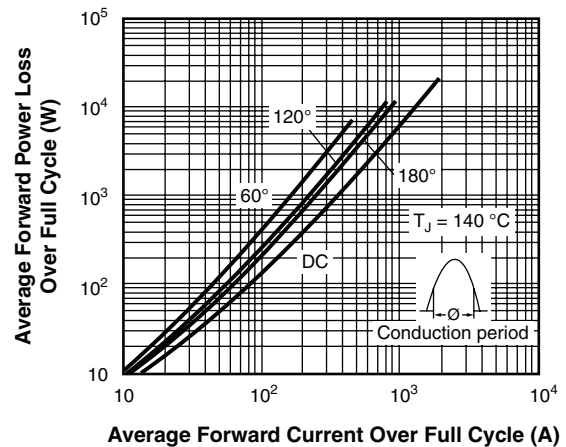


Fig. 4 - Maximum High Level Forward Power Loss vs. Average Forward Current

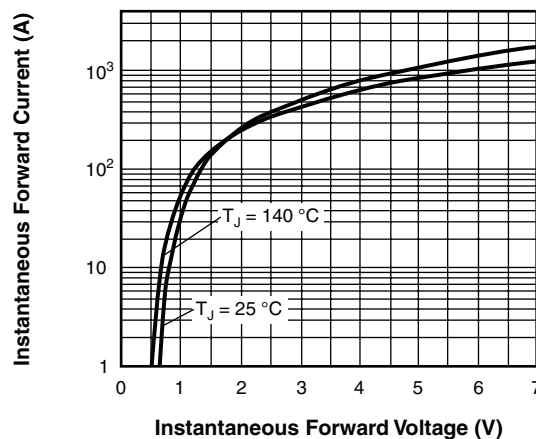


Fig. 5 - Maximum Forward Voltage vs. Forward Current

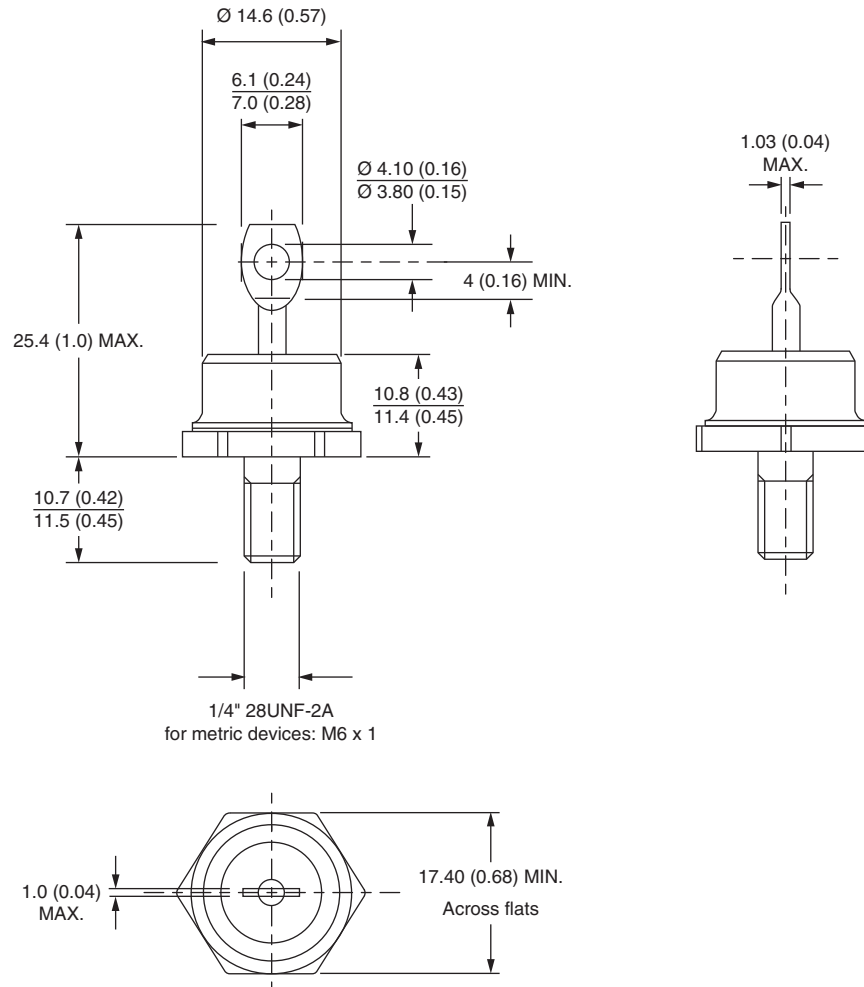
LINKS TO RELATED DOCUMENTS

Dimensions

www.vishay.com/doc?95360

DO-203AB (DO-5) for 1N1183, 1N3765, 1N1183A, 1N2128A, 1N3208 Series

DIMENSIONS in millimeters (inches)





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